

Solid Tantalum Surface Mount Chip Capacitors, Molded Case, 0805 Size



PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +125 °C (above +85 °C, voltage derating is required) Capacitance Range: 0.1 μ F to 47 μ F Capacitance Tolerance: \pm 10 %, \pm 20 %

Voltage Rating: 2.5 V_{DC} to 25 V_{DC}

FEATURES

- · Small size, suitable for high-density packaging
- Terminations: 100 % matte tin
- Qualified to EIA-717
- Compatible with "high volume" automatic pick and place equipment
- Moisture sensitivity level 1
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS

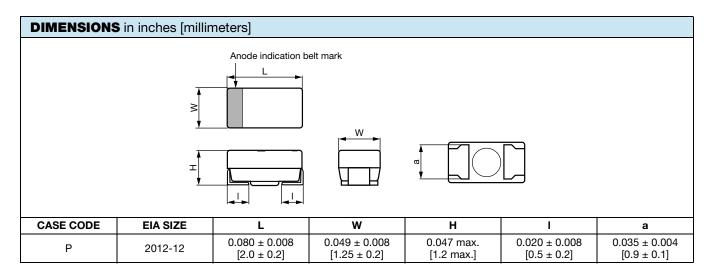
FREE Available

(5-2008) Available

APPLICATIONS

- Industrial
- · Audio and visual equipment
- · General purpose

ТМС	Р	0J	107	M	TR	(2)	F
TYPE	CASE CODE See Ratings and Case Codes table.	DC VOLTAGE RATING AT +85 °C OE = 2.5 V OG = 4.0 V OJ = 6.3 V 1A = 10 V 1C = 16 V 1D = 20 V 1E = 25 V	CAPACITANCE (µF) This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	CAPACITANCE TOLERANCE K = ± 10 % M = ± 20 %	PACKAGING POLARITY I TR = 7" reel, cathodes close to perforation side	OPTIONAL Halogen-free (special order)	F = lead (Pb)-free terminations





www.vishay.com

Vishay Polytech

ATINGS AND CASE CODES							
μF	2.5 V	4.0 V	6.3 V	10 V	16 V	20 V	25 V
0.10						Р	Р
0.15						Р	
0.22						Р	
0.33						Р	
0.47						Р	Р
0.68						Р	
1.0					Р	Р	Р
1.5				Р	Р	Р	
2.2				Р	Р	Р	
3.3				Р	Р		
4.7			Р	Р	Р		
6.8			Р	Р			
10			Р	Р			
15	Р	Р	Р				
22	Р	Р	Р				
33	Р	Р					
47	Р	Р					

MARKING							
		Anode	indication belt mark				
		Simpli voltag	fied code of rated e (D: 20 V)	Simplified or capacitance	ode of nominal ε (A: 0.1 μF)		
SIMPLIFIED V	OLTAGE AND CA	P CODES				1	
μF	2.5	4.0	6.3	10	16	20	25
0.10						DA	E <u>A</u>
0.15						DE	
0.22						DJ	
0.33						DN	
0.47						DS	ES
0.68						DW	
1.0					CA	DĀ	EA
1.5				AE	CE	DĒ	
2.2				AJ	CJ	DJ	
3.3				AN	CN		
4.7			JS	AS	CS		
6.8			JW	AW			
10			JA	aA			
15	eE	GE	jΕ				
22	eJ	gJ	jJ				
33	eN	gN					
47	eS	GS					



STANDARD	RATINGS						
CAPACITANCE (µF)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μΑ)	MAX. DF AT 25 °C, 120 Hz (%)	MAX. ESR AT +25 °C, 100 kHz (Ω)	MAX. RIPPLE, 100 kHz I _{RMS} (A)	
			Γ +85 °C; 1.6 V _{DC}	AT +125 °C			
15	Р	TMCP0E156(1)TRF	0.5	8	4.0	0.126	
22	Р	TMCP0E226(1)TRF	0.6	10	4.0	0.126	
33	Р	TMCP0E336(1)TRF	0.8	20	4.0	0.126	
47	Р	TMCP0E476MTRF	11.8	30	6.0	0.103	
		4 V _{DC} AT	+85 °C; 2.5 V _{DC} A	AT +125 °C			
15	Р	TMCP0G156(1)TRF	0.6	8	4.0	0.126	
22	Р	TMCP0G226(1)TRF	0.9	10	4.0	0.126	
33	Р	TMCP0G336(1)TRF	13.2	30	5.9	0.104	
47	Р	TMCP0G476MTRF	18.8	30	6.0	0.103	
6.3 V _{DC} AT +85 °C; 4 V _{DC} AT +125 °C							
4.7	Р	TMCP0J475(1)TRF	0.5	8	4.0	0.126	
6.8	Р	TMCP0J685(1)TRF	0.5	8	4.0	0.126	
10	Р	TMCP0J106(1)TRF	0.7	8	5.3	0.110	
15	P	TMCP0J156(1)TRF	1.0	12	5.9	0.104	
22	Р	TMCP0J226MTRF	13.9	30	5.9	0.104	
			+85 °C; 6.3 V _{DC}				
1.5	Р	TMCP1A155(1)TRF	0.5	8	11.0	0.076	
2.2	Р	TMCP1A225(1)TRF	0.5	8	8.8	0.085	
3.3	Р	TMCP1A335(1)TRF	0.5	8	7.7	0.091	
4.7	P	TMCP1A475(1)TRF	0.5	8	4.0	0.126	
6.8	P	TMCP1A685(1)TRF	0.7	20	4.0	0.126	
10	Р	TMCP1A106(1)TRF	10.0	20	5.9	0.104	
			Γ +85 °C; 10 V _{DC} /				
1.0	P	TMCP1C105(1)TRF	0.5	6	9.9	0.080	
1.5	P	TMCP1C155(1)TRF	0.5	8	11.0	0.076	
2.2	P P	TMCP1C225(1)TRF	0.5	8 8	8.8	0.085	
3.3 4.7	P P	TMCP1C335(1)TRF	0.6 0.8	8 8	8.8 8.8	0.085	
4.7	Р	TMCP1C475MTRF			0.0	0.085	
0.10	Р		Γ +85 °C; 13 V _{DC} /		00.0	0.044	
0.10	P P	TMCP1D104(1)TRF	0.5	6	33.0	0.044	
0.15 0.22	P P	TMCP1D154(1)TRF TMCP1D224(1)TRF	0.5 0.5	6 6	27.5 27.5	0.048 0.048	
0.22	P P	TMCP1D224(1)TRF TMCP1D334(1)TRF	0.5 0.5	6	27.5 22.0	0.054	
0.33	P	TMCP1D334(1)TRF	0.5 0.5	6	22.0	0.054	
0.47	P	TMCP1D474(1)TRF	0.5	6	16.5	0.062	
1.0	r P	TMCP1D105(1)TRF	0.5	6	11.0	0.076	
1.5	P	TMCP1D155(1)TRF	0.5	8	11.0	0.076	
2.2	r P	TMCP1D225MTRF	0.5	8	8.8	0.085	
			Γ +85 °C; 16 V _{DC} /		0.0	0.000	
0.10	P	TMCP1E104(1)TRF	0.5	6	33.0	0.044	
0.47	r P	TMCP1E474(1)TRF	0.5	6	22.0	0.054	
1.0	Р	TMCP1E105(1)TRF	0.5	6	11.0	0.076	
1.0	Р	IMCP1E105(1)TRF	0.5	6	11.0	0.076	

Note

⁽¹⁾ Tolerance: For 10 % tolerance, specify "K"; for 20 % tolerance, change to "M"

RECOMMENDED VOLTAGE DERATING GUIDELINES (for temperature below +85 °C)					
CAPACITOR VOLTAGE RATING	OPERATING VOLTAGE				
2.5	1.2				
4.0	2.0				
6.3	3.1				
10	5.0				
16	8.0				
20	10.0				
25	12.5				

[•] Part number definition:



POWER DISSIPATION						
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR					
Р	0.064					

STANDARD PACKAGING QUANTITY				
CASE CODE	UNITS PER 7" REEL			
Р	3000			

ITEM	CONDITION	POST TEST	PERFORMA	NCE			
			Specified initial value	-55 °C	+85 °C	+125 °C	
		Capacitance change	-	-20 % to 0 %	0 % to +20 %	0 % to +20 %	
			6	10	8	10	
			8	12	10	12	
Temperature	Measure the specified characteristics in	Dissipation	10	14	12	14	
characteristics	each stage	factor (%)	12	16	14	16	
			20	24	22	24	
			30	60	30	40	
		Leakage current	Refer to Standard Ratings table	-	1000 % specified intial value or less	1250 % specified intial value or less	
	Solder dip:	Capacitance change		Within ± 20 % of initial value			
Solder heat resistance	260 °C ± 5 °C 10 s ± 1 s Reflow:	Dissipation factor		Initial specified value or less			
resistance	260 °C 10 s ± 1 s	Leakage current		Initial specified value or less			
Moisture		Capacitance change		Within ± 20 % of initial value			
resistance	Leave at 40 °C and 90 % to 95 % RH for 500 h	Dissipation factor		Shall not exceed 150 % of initial specified value			
no load	90 /0 10 93 /0 1111101 300 11	Leakage current		Initial specified value or less			
High		Capacitance change		Within ± 20 % of initial value			
temperature	85 °C. The rated voltage is applied for 2000 h	Dissipation fa	Dissipation factor		Initial specified value or less		
load	2000 11	Leakage current		Shall not exceed 200 % of initial specified value			
	Leave at -55 °C, normal temperature,	Capacitance	change	Within ± 20 % of initial value			
Thermal shock	125 °C, and normal temperature for 30 min, 3 min, 30 min, and 3 min.	Dissipation fa	ctor	Initial specified value or less			
	Repeat this operation 5 times running	Leakage current		Initial specified value or less			
Moisture		Capacitance	Capacitance change		Within ± 20 % of initial value or less		
resistance	Leave at 40 °C and 90 % to 95 % RH The rated voltage is applied for 500 h	Dissipation factor		Shall not exceed 150 % of initial specified value			
load	The fated voltage is applied for 500 ff	Leakage current		Shall not exceed 200 % of initial specified value			
Failure rate	85 °C. The rated voltage is applied through a protective resistor of 1 Ω /V.	1 % / 1000 h					

Note

• Test conditions per JIS C5101-1



Guide for Tantalum and Niobium Solid Electrolyte Chip Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS				
DIELECTRIC	e DIELECTRIC CONSTANT			
Air or vacuum	1.0			
Paper	2.0 to 6.0			
Plastic	2.1 to 6.0			
Mineral oil	2.2 to 2.3			
Silicone oil	2.7 to 2.8			
Quartz	3.8 to 4.4			
Glass	4.8 to 8.0			
Porcelain	5.1 to 5.9			
Mica	5.4 to 8.7			
Aluminum oxide	8.4			
Tantalum pentoxide	26			
Ceramic	12 to 400K			

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the leadframe.

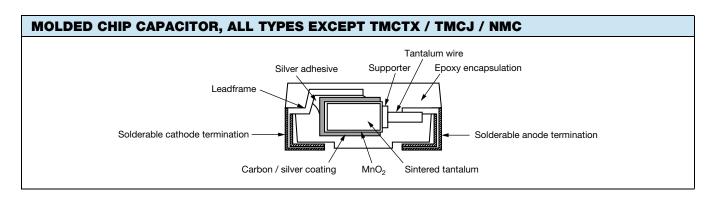
Molded chip tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost.

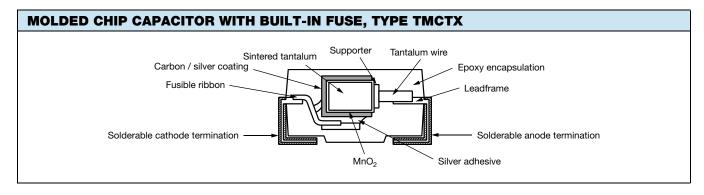
Surface mount designs of "Solid Tantalum" capacitors use lead frames as shown in the accompanying drawings.

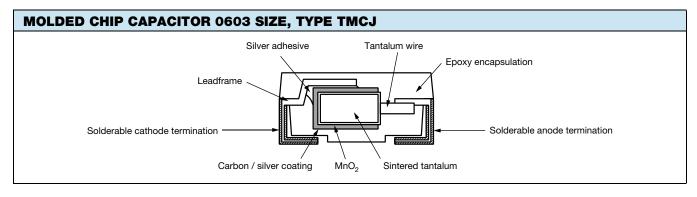
TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

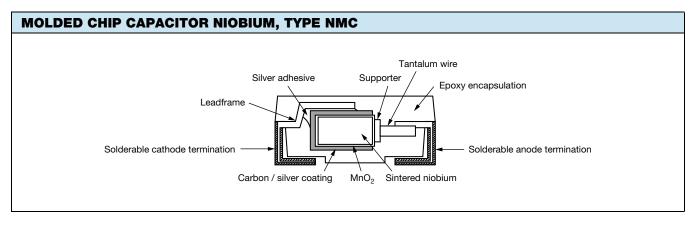
Datasheets covering the various types and styles of capacitors for consumer and entertainment electronics and industry applications are available where detailed performance characteristics must be specified.











SOLID TANT	SOLID TANTALUM CAPACITORS - MOLDED CASE						
SERIES	TMCS	ТМСМ	TMCR	TMCU	TMCP	TMCJ	
PRODUCT IMAGE	*			TEST MATE	MOH	MAJ	
TYPE		Solid tar	ntalum surface mou	nt chip capacitors, molo	led case		
FEATURES	Standard industrial grade	Standard industrial grade extended range	Low ESR	Low profile	0805 size	0603 size	
TEMPERATURE RANGE			-55 °C	to +125 °C			
CAPACITANCE RANGE	0.1 μF to 68 μF	0.47 μF to 470 μF	10 μF to 330 μF	0.1 μF to 220 μF	0.1 μF to 47 μF	0.68 μF to 22 μF	
VOLTAGE RANGE	4 V to 35 V	2.5 V to 35 V	7 V to 35 V	2.5 V to 35 V	2.5 V to 25 V	2.5 V to 20 V	
CAPACITANCE TOLERANCE			± 10 %, ± 20 %			± 20 %	
LEAKAGE CURRENT	0.01 CV or 0.5 μA, whichever is greater						
DISSIPATION FACTOR	4 % to 6 %	4 % to 30 %	6 % to 30 %	4 % to 30 %	6 % to 30 %	20 %	
CASE SIZES	A, B, C, E	A, B, C, E	B, C, E	UA, UB	Р	J	
TERMINATION FINISH	100 % tin Case UA: 100 % tin Case UB: Ni / Pd / A				100	% tin	



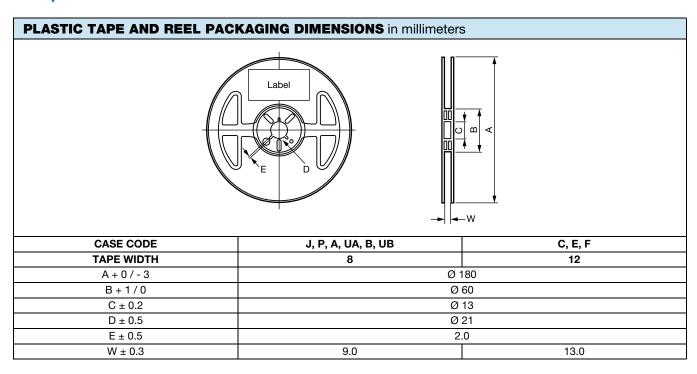
www.vishay.com

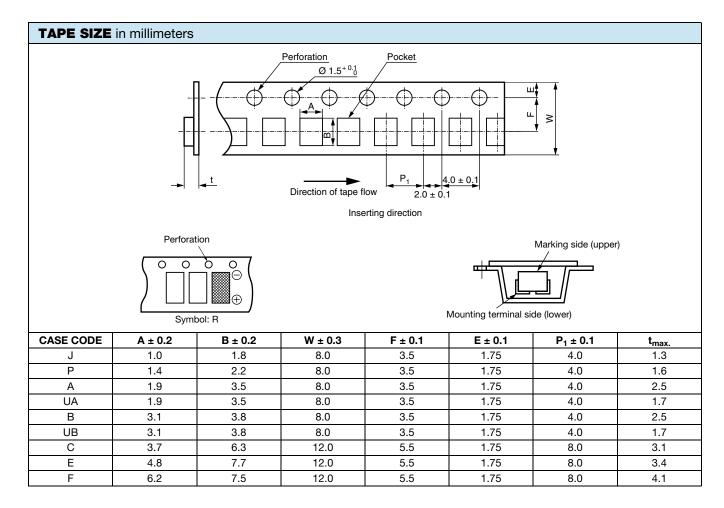
Vishay Polytech

SOLID TANTALUM CAPACITORS - MOLDED CASE					
SERIES	тмстх	тмсн	THC		
PRODUCT IMAGE		14/60	22.65		
TYPE	Solid tantalum surface mount chip capacitors, molded case				
FEATURES	Built-in fuse	High reliability	High reliability, high temperature +150 °C		
TEMPERATURE RANGE	-55 °C to	-55 °C to +150 °C			
CAPACITANCE RANGE	1.0 μF to 68 μF	0.1 μF to 100 μF	0.33 μF to 47 μF		
VOLTAGE RANGE	10 V to 35 V	4 V to 35 V	10 V to 35 V		
CAPACITANCE TOLERANCE	± 10 %, ± 20 %				
LEAKAGE CURRENT	0.01 CV or 0.5 μA, whichever is greater 0.005 CV or 0.25		uA, whichever is greater		
DISSIPATION FACTOR	4 % to 6 %	4 % to 8 %	4 % to 6 %		
CASE SIZES	B, C, E, F	A, B, C, E, P	A, B, C, E		
TERMINATION FINISH	100 % tin				

SOLID NIOBIUM CAPACITORS - MOLDED CASE							
SERIES	NMC	NMCU					
PRODUCT IMAGE	Tien India	iste little					
TYPE	Solid niobium surface mount chip capacitors, molded case						
FEATURES	Flame retardant	Flame retardant, low profile					
TEMPERATURE RANGE	-55 °C to +105 °C						
CAPACITANCE RANGE	10 μF to 470 μF	4.7 μF to 47 μF					
VOLTAGE RANGE	2.5 V t	o 10 V					
CAPACITANCE TOLERANCE	± 20	0 %					
LEAKAGE CURRENT	0.02 CV	or less					
DISSIPATION FACTOR	8 % to 30 %	30 %					
CASE SIZES	A, B, C, E	UA, UB					
TERMINATION FINISH	100 % tin	Case UA: 100 % tin Case UB: Ni / Pd / Au					







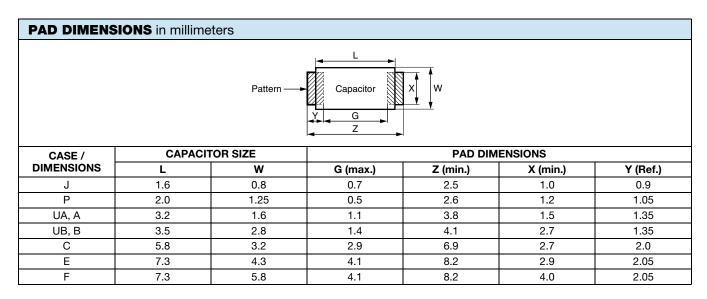


Time from 25 °C to peak temperature

RECOMMENDED REFLOW PROFILES Capacitors should withstand reflow profile as per J-STD-020 standard $\rm T_{\rm C}$ - 5 °C Max. ramp-up rate = 3 °C/s Max. ramp-down rate = 6 °C/s remperature (°C) Preheat area 25 Time 25 °C to peak TIME (s) PROFILE FEATURE **LEAD (Pb)-FREE ASSEMBLY** Preheat / soak Temperature min. (T_{s min.}) 130 °C Temperature max. (T_{s max.}) 160 °C Time (t_s) from (T_{s min.} to T_{s max.)} 60 s to 120 s Ramp-up Ramp-up rate (T_L to T_p) 3 °C/s max. Liquidus temperature (T_L) 200 °C Time (t_L) maintained above T_L 50 s max. Depends on case size - see table below Peak package body temperature (Tp) max. Time (t_p) within 5 °C of the peak maximum temperature 10 s max. Ramp-down rate (Tp to TL) 6 °C/s max.

PEAK PACKAGE BODY TEMPERATURE (Tp)		
CASE CODE	PEAK PACKAGE BODY TEMPERATURE (Tp)	
	LEAD (Pb)-FREE PROCESS	
J, P, UA, A, UB, B, C	260 °C	
E, F	250 °C	

8 min max.



GUIDE TO APPLICATION

 AC Ripple Current: the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where.

P = power dissipation in W at +25 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{\text{RMS}} \, = \, Z \sqrt{\frac{P}{R_{\text{ESR}}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

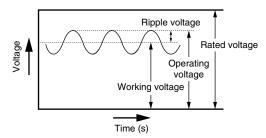
where.

P = power dissipation in W at +25 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

2.1 The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



3. **Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +25 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR		
TEMPERATURE	TMC	NMC
≤ 25 °C	1.0	1.0
85 °C	0.9	0.9
105 °C	0.65	0.4
125 °C	0.4	-

4. Reverse Voltage: the capacitors are not intended for use with reverse voltage applied. If the application of an reverse voltage is unavoidable, it must not exceed the following values:

At 25 °C: 10 % of the rated voltage or 1 V, whichever is smaller.

At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.

5. Mounting Precautions:

5.1 Limit Pressure on Capacitor Installation with Mounter: pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

5.2 Flux Selection

- 5.2.1 Select a flux that contains a minimum of chlorine and amine.
- 5.2.2 After flux use, the chlorine and amine in the flux remain must be removed.
- 5.3 Cleaning After Mounting: the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.
 - Halogen organic solvent (HCFC225, etc.)
 - Alcoholic solvent (IPA, ethanol, etc.)
 - Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur.
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout.



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

```
TMCP0E156MTRF TMCP0E226MTRF TMCP0E336MTRF TMCP0E476MTRF TMCP0G156MTRF
TMCP0G226MTRF TMCP0G336MTRF TMCP0G476MTRF TMCP0J475MTRF TMCP0J685MTRF
TMCP0J106MTRF TMCP0J156MTRF TMCP0J226MTRF TMCP1A155MTRF TMCP1A225MTRF TMCP1A335MTRF
 TMCP1A475MTRF TMCP1A685MTRF TMCP1A106MTRF TMCP1C105MTRF TMCP1C155MTRF
TMCP1C225MTRF TMCP1C335MTRF TMCP1C475MTRF TMCP1D104MTRF TMCP1D154MTRF
TMCP1D224MTRF TMCP1D334MTRF TMCP1D474MTRF TMCP1D684MTRF TMCP1D105MTRF
TMCP1D155MTRF TMCP1D225MTRF TMCP1E104MTRF TMCP1E474MTRF TMCP1E105MTRF
TMCP0E156MTR2F TMCP0E226MTR2F TMCP0E336MTR2F TMCP0E476MTR2F TMCP0G156MTR2F
TMCP0G226MTR2F TMCP0G336MTR2F TMCP0G476MTR2F TMCP0J475MTR2F TMCP0J685MTR2F
TMCP0J106MTR2F TMCP0J156MTR2F TMCP0J226MTR2F TMCP1A155MTR2F TMCP1A225MTR2F
TMCP1A335MTR2F TMCP1A475MTR2F TMCP1A685MTR2F TMCP1A106MTR2F TMCP1C105MTR2F
TMCP1C155MTR2F TMCP1C225MTR2F TMCP1C335MTR2F TMCP1C475MTR2F TMCP1D104MTR2F
TMCP1D154MTR2F TMCP1D224MTR2F TMCP1D334MTR2F TMCP1D474MTR2F TMCP1D684MTR2F
TMCP1D105MTR2F TMCP1D155MTR2F TMCP1D225MTR2F TMCP1E104MTR2F TMCP1E474MTR2F
TMCP1E105MTR2F TMCP0E156KTRF TMCP0E226KTRF TMCP0E336KTRF TMCP0G156KTRF
TMCP0G226KTRF TMCP0G336KTRF TMCP0J475KTRF TMCP0J685KTRF TMCP0J106KTRF TMCP0J156KTRF
TMCP1A155KTRF TMCP1A225KTRF TMCP1A335KTRF TMCP1A475KTRF TMCP1A685KTRF TMCP1A106KTRF
 TMCP1C105KTRF TMCP1C155KTRF TMCP1C225KTRF TMCP1C335KTRF TMCP1D104KTRF
TMCP1D154KTRF TMCP1D224KTRF TMCP1D334KTRF TMCP1D474KTRF TMCP1D684KTRF TMCP1D105KTRF
 TMCP1D155KTRF
```